## Supporting Information

## On the Role of Plasmonic Ti<sub>3</sub>C<sub>2</sub>T<sub>x</sub> MXene in Enhancing Photoredox Catalysis

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Figure S1. Zeta potentials of the as-prepared samples.



Figure S2. XRD patterns of TiO<sub>2</sub>, TC, and TC-MX composites.



Figure S3. SEM image of TiO<sub>2</sub> nanosheets.



Figure S4. SEM images of (a) TC-1, (b) TC-2, and (c) TC-3.



Figure S5. HAADF-STEM image of TC-2 with the corresponding Ti, O, Cd, and S EDX mapping results.



**Figure S6.** (a) SEM and (b) TEM images of  $Ti_3C_2T_x$ .



Figure S7. SEM image of TC-0.1MX.



Figure S8. XPS spectrum of TC-0.1MX: (a) Survey, (b) C 1s, (c) O 1s and (d) Ti 2p.



Figure S9. Ultraviolet-visible-NIR light absorption spectrum of  $Ti_3C_2T_x$  colloid.



**Figure S10**. (a) SEM image of TC-0.1RGO. (b) UV-vis diffuse reflectance spectra (DRS) of TC-0.1MX and TC-0.1RGO composites.



Figure S11. UV-vis absorption spectra of 4-NA aqueous solution over TC-0.1MX nanocomposite under visible light irradiation ( $\lambda > 420$  nm) with the addition of ammonium formate as quencher for photogenerated holes under N<sub>2</sub> purge.



**Figure S12**. Transformed plots based on the Kubelka–Munk function versus photon energy for TC-2.

**Note:** As  $TiO_2$  has no light absorption in the visible region of  $TiO_2@CdS$  (**Figure 2c**), the  $E_g$  obtained corresponds to CdS.



Figure S13. XPS valence band spectrum of TC-2.

**Note:** The valence band energy ( $E_{VB}$ ) of TiO<sub>2</sub>@CdS composite is attributed to CdS by XPS, because CdS is coated on the surface of CdS and the XPS detection depth is only ~5 nm.



Figure S14. Mott-Schottky plots of TiO<sub>2</sub>.

**Note:** It is seen from **Figure S14** that the flat-band potential of  $TiO_2$  is estimated to be around -0.67 V versus Ag/AgCl (pH = 6.8, for 0.2 M Na<sub>2</sub>SO<sub>4</sub> electrolyte). It is known that the bottom of conduction band in n-type semiconductors is more negative by about -0.2 V than the flat band potential<sup>[1]</sup>. The conduction band of  $TiO_2$  is calculated to be -0.27 V versus normal hydrogen electrode (NHE, pH = 0)<sup>[2]</sup>.



**Figure S15**. Photocurrent densities of TC-1, TC-2, and TC-3 under visible-NIR light irradiation  $(\lambda > 420 \text{ nm}).$ 



Figure S16. Photoactivities of TC-0.1RGO a) and TC-0.2RGO b) composites for the selective reduction of 4-nitroaniline (4-NA) to 4-phenylenediamine (4-PDA) in water with the addition of ammonium formate as a hole scavenger and N<sub>2</sub> purging in water under visible-NIR light irradiation ( $\lambda > 420$  nm).



Figure S17. Control experiments for photocatalytic reduction of 4-NA over TC-0.1MX: reaction with  $K_2S_2O_8$  as a scavenger for electrons, and reaction without the purge of  $N_2$ , without light, without catalyst.



Figure S18. UV-vis absorption spectra of 4-NA over TC-0.1MX under adsorption equilibrium.



Figure S19. Stability test of TC-0.1MX.



Figure S20. SEM images of (a) the original TC-0.1MX sample, and the TC-0.1MX sample

after (b) three-cycle photocatalysis reactions.



Figure S21. XRD patterns of the TC-0.1MX sample before and after three-cycle photocatalysis

reactions.



Figure S22. Ultraviolet photoelectron spectra (UPS) of the synthesized  $Ti_3C_2T_x$  MXene.

Note: The excitation source was He I (hv = 21.22 eV) and a negative bias of -9.8 eV was applied during the UPS measurement. The following formula is used to calculate the work function ( $\Phi$ ) of Ti<sub>3</sub>C<sub>2</sub>T<sub>x</sub>:

$$\Phi = hv - W = 21.22 - 16.91 = 4.31 \text{ eV}$$

where W is the width of the UPS spectrum. Then, the Fermi level ( $E_F$ ) of  $Ti_3C_2T_x$  is calculated as follows<sup>[3]</sup>:

$$E_F = E_{vac} - \Phi$$

where  $E_{vac}$  is the energy of a stationary electron at vacuum level (assumed as 0 eV). Therefore, it can be estimated that the  $E_F$  of the  $Ti_3C_2T_x$  is located at -4.31 eV vs. vacuum level. According to the relationship between the Evac and the normal electrode potential ( $E_{NHE}$ ),  $E_{vac} = -E_{NHE} 4.44^{[3]}$ , the  $E_F$  of  $Ti_3C_2T_x$  is thus determined to be -0.13 V vs. normal hydrogen electrode.



Figure S23. Mott-Schottky plots of TC-2 and TC-0.1MX.

**Note:** The flat band potential is obtained from the Mott-Schottky curve corresponding to the apparent Fermi level after the Fermi-level equilibration of the different components.



Figure S24. Photoactivities of TC-0.1MX for selective reduction of 4-NA under light irradiation ( $\lambda > 780$  nm) at room temperature.



**Figure S25**. The finite-difference time-domain (FDTD) model consisting of CdS deposited to  $TiO_2$  and then loaded to  $Ti_3C_2T_x$ .



Figure S26. FDTD simulation of the near-field distributions of  $Ti_3C_2T_x$ .



Figure S27. (a) Mott-Schottky plots for TC-2 and TC-0.1MX composites under 1 sun irradiation and (b) corresponding calculated results of the photo-induced carrier concentration. Note: As shown in Figure S27, the slope of C<sup>-2</sup> vs. *V* in the Mott-Schottky plot of TC-0.1MX decreases as compared to that of TC-2, indicating the increase of charge carriers density. The charge carriers density ( $N_D$ ) is calculated to be  $3.7 \times 10^{19}$  and  $7.5 \times 10^{19}$  cm<sup>-3</sup> for TC-2 and TC-0.1MX, respectively, according to the following equation<sup>[4]</sup>.

$$N_D = \frac{2}{\varepsilon \varepsilon \varepsilon_0} \left( \frac{dl (1 / C^2)}{dl V} \right)^{-1}$$

where *e* is the elementary electronic charge,  $\varepsilon$  is the dielectric constant (8.99 for CdS<sup>[5]</sup>),  $\varepsilon_0$  is the permittivity in vacuum, *C* is the capacitance, and *V* is the applied potential.



Figure S28. Time-resolved PL decay of TC-2 and TC-0.1MX.



**Figure S29**. (a) Decay curves of photovoltage, and (b) electron lifetime of TC-2 and TC-MX composites.



Figure S30. EIS Nyquist plots of the samples.



**Figure S31**. Cyclic voltammetry curves of TC-2 and TC-0.1MX composites at different scan rates.



**Figure S32**. The top view of optimized calculation models of (a)  $TiO_2$ , (b) CdS, (c)  $Ti_3C_2T_x$  and (d) TC-MX.

Table S1. XRD intensities of TiO<sub>2</sub> (224) and CdS (110) for different TC composites

Entry	TC-1	TC-2	TC-3
TiO <sub>2</sub> (224)	266	260	235
CdS (110)	545	460	344
Ratio of $TiO_2$ (224) to CdS	0.49	0.57	0.68
(110)			

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